RoHS

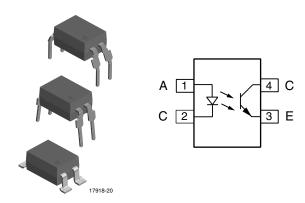
COMPLIANT

GREEN (5-2008)\*\*



## Vishay Semiconductors

# Optocoupler, Phototransistor Output, High Reliability, 5000 V<sub>RMS</sub>, 110 °C Rated



#### **DESCRIPTION**

The 110 °C rated SFH1617A (DIP) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400  $V_{RMS}$  or DC. Specifications subject to change.

#### **FEATURES**

- Operating temperature from 55 °C to + 110 °C
- Good CTR linearity depending on forward current



- High collector emitter voltage, V<sub>CFO</sub> = 70 V
- Low saturation voltage
- · Fast switching times
- Low CTR degradation
- Temperature stableIE
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### Note

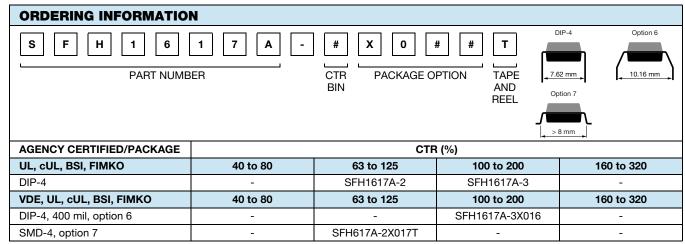
\*\* Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

#### **APPLICATIONS**

- AC adapter
- SMPS
- PLC
- · Factory automation
- · Game consoles

#### **AGENCY APPROVALS**

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending) available with option 1
- BSI EN 60950; EN 60065
- FIMKO
- CQC (pending)



#### Note

· Additional options may be possible, please contact sales office.



# Vishay Semiconductors

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V <sub>R</sub>	6.0	V			
DC forward current		I <sub>F</sub>	60	mA			
Surge forward current	t ≤ 10 μs	I <sub>FSM</sub>	2.5	Α			
LED power dissipation		P <sub>diss</sub>	70	mW			
OUTPUT							
Collector emitter voltage		$V_{CEO}$	70	V			
Emitter collector voltage		V <sub>ECO</sub>	7.0	V			
Collector current		I <sub>C</sub>	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA			
Output power dissipation		P <sub>diss</sub>	150	mW			
COUPLER							
Isolation test voltage between emitter and detector, refer to climate DIN 40046, part 2, Nov. 74		V <sub>ISO</sub>	5000	V <sub>RMS</sub>			
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω			
isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω			
Storage temperature range		T <sub>stg</sub>	- 55 to + 150	°C			
Ambient temperature range		T <sub>amb</sub>	- 55 to + 110	°C			
Soldering temperature (1)	2 mm from case, ≤ 10 s	T <sub>sld</sub>	260	°C			

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT	INPUT							
Forward voltage	$I_F = 60 \text{ mA}$		$V_{F}$		1.35	1.65	V	
Reverse current	V <sub>R</sub> = 6.0 V		I <sub>R</sub>		0.01	10	μΑ	
Capacitance	$V_R = 0 V, f = 1.0 MHz$		Co		13		pF	
OUTPUT								
Collector emitter capacitance	$V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$		$C_{CE}$		5.2		pF	
	V 10.V	SFH1617A-1	I <sub>CEO</sub>		2.0	50	nA	
Collector emitter leakage current		SFH1617A-2	I <sub>CEO</sub>		2.0	50	nA	
	V <sub>CE</sub> = 10 V	SFH1617A-3	I <sub>CEO</sub>		5.0	100	nA	
		SFH1617A-4	I <sub>CEO</sub>		5.0	100	nA	
COUPLER								
Collector emitter saturation voltage	I <sub>F</sub> = 10 mA, f = 1.0 MHz		V <sub>CEsat</sub>		0.25	0.4	V	
Coupling capacitance			C <sub>C</sub>		0.4	_	pF	

#### Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.



# Vishay Semiconductors

CURRENT TRAN	IT TRANSFER RATIO ( $T_{amb} = 25$ °C, unless otherwise specified)   IR   TEST CONDITION   PART   SYMBOL   MIN.   TYP.   MAX.   UNIT						
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		SFH1617A-1	CTR	40		80	%
	I 10 m/ V 5 0 V	SFH1617A-2	CTR	63		125	%
I <sub>O</sub> /I <sub>F</sub>	1F = 10 111A, VCE = 3.0 V	SFH1617A-3	CTR	100		200	%
		SFH1617A-4	CTR	160		320	%
		SFH1617A-1	CTR	13	30		%
	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	SFH1617A-2	CTR	22	45		%
		SFH1617A-3	CTR	34	70		%
		SFH1617A-4	CTR	56	90		%

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Turn-on time	$I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$		t <sub>on</sub>		3.0		μs
Rise time	$I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$		t <sub>r</sub>		2.0		μs
Turn-off time	$I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$		t <sub>off</sub>		2.3		μs
Fall time	$I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$		t <sub>f</sub>		2.0		μs
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}$		f <sub>ctr</sub>		100		kHz
SATURATED							
	I <sub>F</sub> = 20 mA	SFH1617A-1	t <sub>on</sub>		3.0		μs
T	I <sub>F</sub> = 10 mA	SFH1617A-2	t <sub>on</sub>		4.2		μs
Turn-on time		SFH1617A-3	t <sub>on</sub>		4.2		μs
	I <sub>F</sub> = 5.0 mA	SFH1617A-4	t <sub>on</sub>		6.0		μs
Rise time	I <sub>F</sub> = 20 mA	SFH1617A-1	t <sub>r</sub>		2.0		μs
	I <sub>F</sub> = 10 mA	SFH1617A-2	t <sub>r</sub>		3.0		μs
		SFH1617A-3	t <sub>r</sub>		3.0		μs
	I <sub>F</sub> = 5.0 mA	SFH1617A-4	t <sub>r</sub>		4.6		μs
Turn-off time	I <sub>F</sub> = 20 mA	SFH1617A-1	t <sub>off</sub>		18		μs
	I <sub>F</sub> = 10 mA	SFH1617A-2	t <sub>off</sub>		23		μs
		SFH1617A-3	t <sub>off</sub>		23		μs
	I <sub>F</sub> = 5.0 mA	SFH1617A-4	t <sub>off</sub>		25		μs
<b>-</b> # 0	I <sub>F</sub> = 20 mA	SFH1617A-1	t <sub>f</sub>		11		μs
	1 10	SFH1617A-2	t <sub>f</sub>		14		μs
Fall time	I <sub>F</sub> = 10 mA	SFH1617A-3	t <sub>f</sub>		14		μs
	I <sub>F</sub> = 5.0 mA	SFH1617A-4	t <sub>f</sub>		15		μs

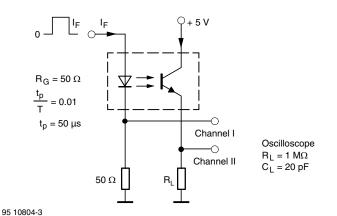


Fig. 1 - Test Circuit, Non-Saturated Operation



#### www.vishay.com

# Vishay Semiconductors

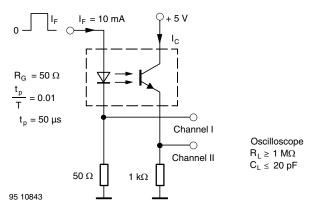
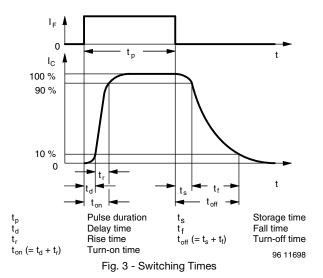


Fig. 2 - Test Circuit, Saturated Operation



SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				55/110/21			
Comparative tracking index		CTI	175		399		
Rated impulse voltage		V <sub>IOTM</sub>			8	kV	
Maximum working voltages	Recurring peak voltage	V <sub>IORM</sub>			890	V	
Forward current		I <sub>SI</sub>			275	mA	
Power dissipation		P <sub>SO</sub>			400	mW	
Safety temperature		T <sub>SI</sub>			175	°C	
Creepage distance			7.0			mm	
Clearance distance			7.0			mm	
Isolation distance	per IEC 60950 2.10.5.1		0.4			mm	

#### Note

According to DIN EN 60747-5-2 (VDE 0884). These optocouplers are suitable for "safe electrical insulation" only within the safety ratings.
 Compliance with the safety ratings shall be ensured by means of protective circuits.



# Vishay Semiconductors

#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

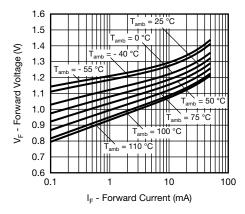


Fig. 4 - Forward Voltage vs. Forward Current

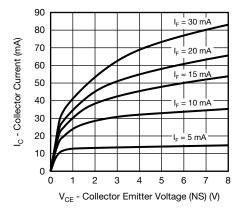


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

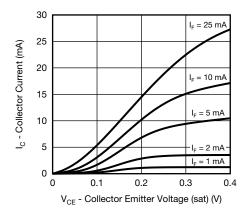


Fig. 6 - Collector Current vs. Collector Emitter Voltage (sat)

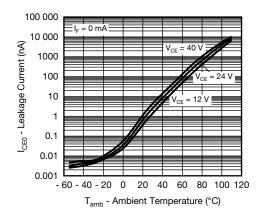


Fig. 7 - Leakage Current vs. Ambient Temperature

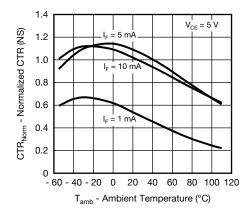


Fig. 8 - Normalized CTR (NS) vs. Ambient Temperature

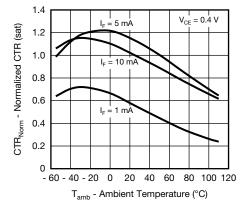
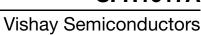


Fig. 9 - Normalized CTR (sat) vs. Ambient Temperature





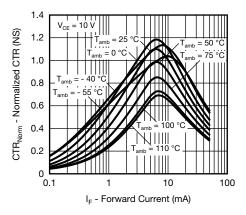


Fig. 10 - Normalized CTR (NS) vs. Forward Current

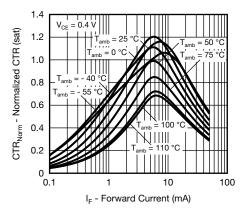


Fig. 11 - Normalized CTR (sat) vs. Forward Current

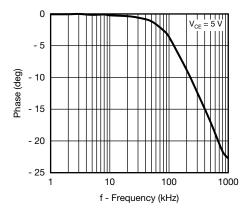


Fig. 12 - CTR Frequency vs. Phase Angle

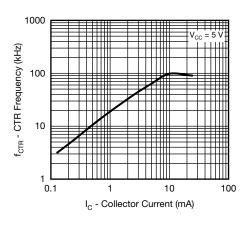


Fig. 13 - CTR Frequency vs. Collector Current

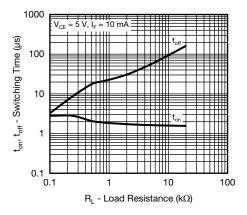
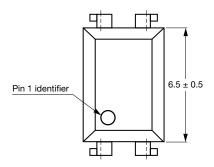
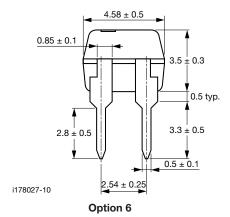


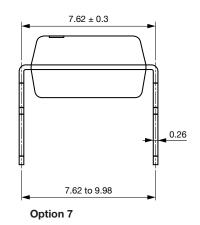
Fig. 14 - Switching Time vs. Load Resistance

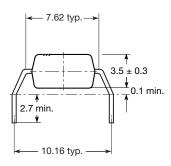


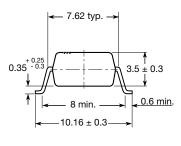
#### **PACKAGE DIMENISONS** in millimeters

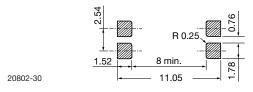












#### **PACKAGE MARKING**



#### Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.



## **Legal Disclaimer Notice**

Vishay

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# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000